



CY74FCT163244 CY74FCT163H244

SCCS046 - December 1996 - Revised March 2000

Features

- Low power, pin-compatible replacement for LCX and LPT families
- 5V tolerant inputs and outputs
- 24 mA balanced drive outputs
- · Power-off disable outputs permits live insertion
- Edge-rate control circuitry for reduced noise
- FCT-C speed at 4.1 ns
- Latch-up performance exceeds JEDEC standard no. 17
- Typical output skew < 250 ps
- Industrial temperature range of -40°C to +85°C
- TSSOP (19.6-mil pitch) or SSOP (25-mil pitch)
- Typical V_{olp} (ground bounce) performance exceeds Mil Std 883D
- V_{CC} = 2.7V to 3.6V
- ESD (HBM) > 2000V

16-Bit Buffers/Line Drivers

CY74FCT163H244

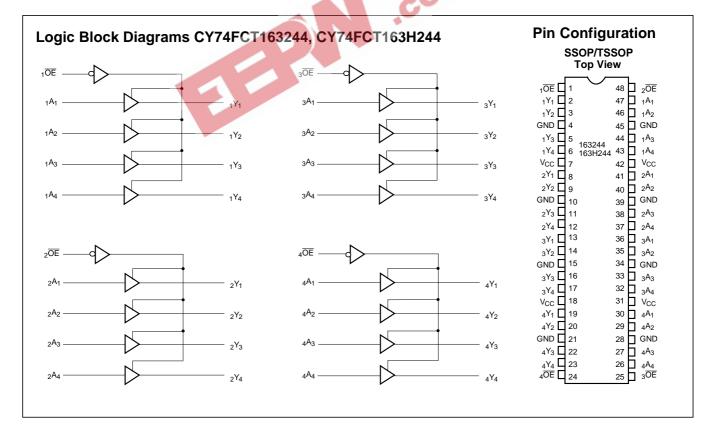
- · Bus hold on data inputs
- Eliminates the need for external pull-up or pull-down resistors
- Devices with bus hold are not recommended for translating rail-to-rail CMOS signals to 3.3V logic levels

Functional Description

These 16-bit buffers/line drivers are designed for use in memory driver, clock driver, or other bus interface applications, where high-speed and low power are required. The three-state controls are designed to allow 4-bit, 8-bit or combined 16-bit operation. Flow-through pinout and small shrink packaging simplifies board layout.

The CY74FCT163244 has 24-mA balanced output drivers with current limiting resistors in the outputs.

The CY74FCT163H244 has "bus hold" on the data inputs, which retains the last state of the input whenever the source driving the input goes to high impedance. This eliminates the need for pull-up/down resistors and prevents floating inputs.



JMENTS

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Pin Description

Name	Description					
OE	Three-State Output Enable Inputs (Active LOW)					
A	Data Inputs ^[1]					
Y	Three-State Outputs					

Function Table^[2]

Inp	Outputs	
OE A		Y
L	L	L
L	Н	Н
Н	Х	Z

Maximum Ratings^[3,4]

(Above which the useful life may be impaired lines, not tested.)	ed. For user guide-
Storage Temperature	–55°C to +125°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage Range	0.5V to +4.6V
DC Input Voltage	–0.5V to +7.0V
DC Output Voltage	–0.5V to +7.0V
DC Output Current (Maximum Sink Current/Pin)	60 to +120 mA
Power Dissipation	1.0W

Operating Range

Range	Ambient Temperature	V _{cc}
Industrial	-40°C to +85°C	2.7V to 3.6V

59 Electrical Characteristics for Non Bus Hold Devices Over the Operating Range V_{CC}=2.7V to 3.6V

Parameter	Description	Test Conditions	Min.	Typ. ^[5]	Max.	Unit
V _{IH}	Input HIGH Voltage	All Inputs	2.0		5.5	V
V _{IL}	Input LOW Voltage				0.8	V
V _H	Input Hysteresis ^[6]			100		mV
V _{IK}	Input Clamp Diode Voltage	V _{CC} =Min., I _{IN} =–18 mA		-0.7	- 1.2	V
I _{IH}	Input HIGH Current	V _{CC} =Max., V _I =5.5			±1	μΑ
IIL	Input LOW Current	V _{CC} =Max., V _I =GND			±1	μΑ
I _{OZH}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT} =5.5V			±1	μA
I _{OZL}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT} =GND			±1	μΑ
l _{os}	Short Circuit Current ^[7]	V _{CC} =Max., V _{OUT} =GND	-60	-135	-240	mA
I _{OFF}	Power-Off Disable	V _{CC} =0V, V _{OUT} ≤4.5V			±100	μA
ICC	Quiescent Power Supply Current	$\begin{array}{ c c c c } & V_{IN} \leq 0.2V, & V_{CC} = I \\ & V_{IN} \geq V_{CC} - 0.2V & \end{array}$	Max.	0.1	10	μΑ
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs HIGH)	V _{IN} =V _{CC} -0.6V ^[8] V _{CC} =N	Max.	2.0	30	μA

Notes:

1. 2.

On the CY74FCT163H244, these pins have "bus hold." H = HIGH Voltage Level. L = LOW Voltage Level. X = Don't Care. Z = High Impedance. Operation beyond the limits set forth may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature 3.

4. 5.

Operation beyond the limits set forth may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range. With the exception of inputs with bus hold, unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground. Typical values are at V_{CC}=3.3V, T_A = +25°C ambient. This parameter is specified but not tested. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last. Per TTL driven input: all other inputs at V_{CC} or GND. 6. 7.

8. Per TTL driven input; all other inputs at V_{CC} or GND.



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Electrical Characteristics For Bus Hold Devices Over the Operating Range V_{CC}=2.7V to 3.6V

Parameter	Description	Test Cond	itions	Min.	Typ. ^[5]	Max.	Unit
V _{IH}	Input HIGH Voltage	All Inputs		2.0		V _{CC}	V
V _{IL}	Input LOW Voltage					0.8	V
V _H	Input Hysteresis ^[6]				100		mV
V _{IK}	Input Clamp Diode Voltage	V _{CC} =Min., I _{IN} =-1	8 mA		-0.7	-1.2	V
I _{IH}	Input HIGH Current	V _{CC} =Max., V _I =V _C	C			±100	μΑ
I _{IL}	Input LOW Current					±100	μΑ
I _{BBH}	Bus Hold Sustain Current on Bus Hold Input ^[9]	V _{CC} =Min.	V _I =2.0V	-50			μA
I _{BBL}			V _I =0.8V	+50			μA
I _{BHHO} I _{BHLO}	Bus Hold Overdrive Current on Bus Hold In- put ^[9]	V _{CC} =Max., V _I =1.5V				±500	μA
I _{OZH}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT}	V _{CC} =Max., V _{OUT} =V _{CC}			±1	μA
I _{OZL}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT}	V _{CC} =Max., V _{OUT} =GND			±1	μA
l _{os}	Short Circuit Current ^[7]	V _{CC} =Max., V _{OUT}	=GND	—60	-135	-240	mA
I _{OFF}	Power-Off Disable	V _{CC} =0V, V _{OUT} ≤4	.5V			±100	μA
I _{CC}	Quiescent Power Supply Current	$V_{IN} \leq 0.2V,$ $V_{IN} \geq V_{CC} = 0.2V$				+40	μA
Δ_{ICC}	Quiescent Power supply Current (TTL inputs HIGH)	V _{IN} =V _{CC} -0.6V ^[8]	V _{CC} =Max.			+350	μA

Electrical Characteristics For Balanced Drive Devices Over the Operating Range V_{CC}=2.7V to 3.6V

Parameter	Description	Test Conditions	Min.	Typ. ^[5]	Max.	Unit
I _{ODL}	Output LOW Dynamic Current ^[7]	V_{CC} =3.3V, V_{IN} = V_{IH} or V_{IL} , V_{OUT} =1.5V	45		180	mA
I _{ODH}	Output HIGH Dynamic Current ^[7]	V_{CC} =3.3V, V_{IN} = V_{IH} or V_{IL} , V_{OUT} =1.5V	-45		-180	mA
V _{OH}	Output HIGH Voltage	V _{CC} =Min., I _{OH} = -0.1 mA	V _{CC} -0.2			V
		V _{CC} =3.0V, I _{OH} = -8 mA	2.4 ^[10]	3.0		V
		V _{CC} =3.0V, I _{OH} = -24 mA	2.0	3.0		V
V _{OL}	Output LOW Voltage	V _{CC} =Min., I _{OL} = 0.1mA			0.2	V
		V _{CC} =Min., I _{OL} = 24 mA		0.3	0.55	

Notes:

9. Pins with bus hold are described in Pin Description. 10. $V_{OH} = V_{CC} - 0.6V$ at rated current.



Capacitance^[6](T_A = +25°C, f = 1.0 MHz)

Parameter	Description	Test Conditions	Typ. ^[5]	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	4.5	6.0	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	5.5	8.0	pF

Power Supply Characteristics

Parameter	Description	Test Condition	ons	Typ. ^[5]	Max.	Unit
I _{CCD}	Dynamic Power Supply Current ^[10]	V _{CC} =Max., One Input Toggling, 50% Duty Cycle, Outputs Open, OE=GND	V _{IN} =V _{CC} or V _{IN} =GND	50	75	μA/MHz
I _C	Total Power Supply Current ^[11]	V _{CC} =Max., f ₁ =10 MHz, 50% Duty Cycle, Outputs Open, One	V _{IN} =V _{CC} or V _{IN} =GND	0.5	0.8	mA
		Bit Toggling, OE=GND	V _{IN} =V _{CC} -0.6V or V _{IN} =GND	0.5	0.8	mA
		V _{CC} =Max., f ₁ =2.5 MHz, 50% Duty Cycle, Outputs Open, Six-	V _{IN} =V _{CC} or V _{IN} =GND	2.0	3.0 ^[12]	mA
		teen Bits Toggling, OE=GND	V _{IN} =V _{CC} -0.6V or V _{IN} =GND	2.0	3.3 ^[12]	mA
Notes:	·					
12. $I_C = I_Q$ $I_C = I_C$ $I_{CC} = Q$ $\Delta I_{CC} = PC$ $D_H = D$ $N_T = N$ $I_{CCD} = D$	Neter is not directly testable, but is deri UIESCENT + INPUTS + IDYNAMIC $C^{+\Delta}I_{CC}D_{H}N_{T}+I_{CCD}(f_0/2 + f_1N_1)$ uiescent Current with CMOS input lew ower Supply Current for a TTL HIGH in uty Cycle for TTL inputs HIGH umber of TTL inputs at D _H ynamic Current caused by an input tra	nput (V _{IN} =3.4V) nsition pair (HLH or L HL)	ions.			

= Input signal frequency f₁

N1 = Number of inputs changing at f1 All currents are in milliamps and all frequencies are in megahertz.
13. Values for these conditions are examples of the I_{CC} formula. These limits are specified but not tested.



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Switching Characteristics Over the Operating Range V_{CC}=3.0V to $3.6V^{[14,15]}$

			T163244A 163H244A		Г163244С 163Н244С		
Parameter	Description	Min.	Max.	Min.	Max.	Unit	Fig. No. ^[16]
t _{PLH} t _{PHL}	Propagation Delay Data to Output	1.5	4.8	1.5	4.1	ns	1, 3
t _{PZH} t _{PZL}	Output Enable Time	1.5	6.2	1.5	5.8	ns	1, 7, 8
t _{PHZ} t _{PLZ}	Output Disable Time	1.5	5.6	1.5	5.2	ns	1, 7, 8
t _{SK(O)}	Output Skew ^[17]		0.5		0.5	ns	—

Notes:

Minimum limits are specified but not tested on Propagation Delays.
For V_{CC} =2.7, propagation delay, output enable and output disable times should be degraded by 20%.
See "Parameter Measurement Information" in the General Information section.
Skew between any two outputs of the same package switching in the same direction. This parameter is ensured by design.

Ordering Information CY74FCT163244

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
4.1	CY74FCT163244CPACT	Z48	48-Lead (240-Mil) TSSOP	Industrial
	CY74FCT163244CPVC/PVCT	O48	48-Lead (300-Mil) SSOP	
4.8	CY74FCT163244APACT	Z48	48-Lead (240-Mil) TSSOP	Industrial
	CY74FCT163244APVC/PVCT	048	48-Lead (300-Mil) SSOP	

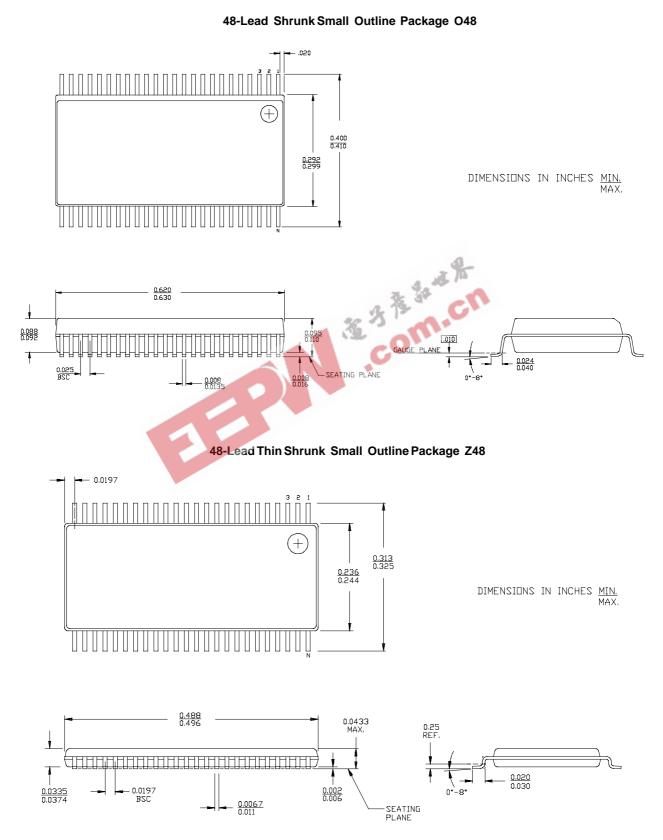
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Ordering Information CY74FCT163H244

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
4.1	74FCT163H244CPACT	Z48	48-Lead (240-Mil) TSSOP	Industrial
	CY74FCT163H244CPVC	O48	48-Lead (300-Mil) SSOP	
	74FCT163H244CPVCT	O48	48-Lead (300-Mil) SSOP	1



Package Diagrams



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